

## Low voltage high performance NPN power transistor

Datasheet - preliminary data

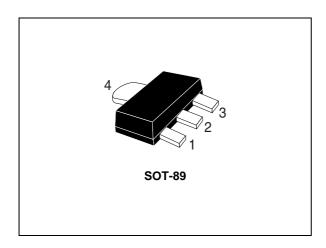
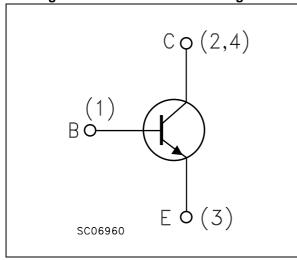


Figure 1. Internal schematic diagram



#### **Features**

- Very low collector-emitter saturation voltage
- High current gain characteristic
- · Fast switching speed

#### **Applications**

- Power management
- DC-DC converters
- Automotive

#### **Description**

This device is a NPN transistor manufactured using new low voltage planar technology with double metal process. The result is a transistor which boasts exceptionally high gain performance coupled with very low saturation voltage.

**Table 1. Device summary** 

Order codes	Marking	Package	Packaging
3STF1640	1640	SOT-89	Tape and reel

Contents 3STF1640

## **Contents**

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3STF1640 Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	40	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	40	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	7	V
I <sub>C</sub>	Collector current	6	А
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 1 ms)	20	А
P <sub>tot</sub>	Total dissipation at T <sub>amb</sub> = 25 °C	1.5	W
T <sub>stg</sub>	Storage temperature -65 to		°C
T <sub>J</sub>	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJA</sub> <sup>(1)</sup>	Thermal resistance junction-ambient max	83	°C/W

<sup>1.</sup> Device mounted on PCB area of 1 cm<sup>2</sup>

Electrical characteristics 3STF1640

## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified.

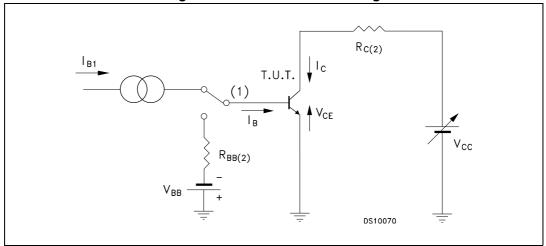
**Table 4. Electrical characteristics** 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 40 V			0.1	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			0.1	μΑ
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	Ι <sub>C</sub> = 100 μΑ	40			V
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA	40			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	Ι <sub>Ε</sub> = 100 μΑ	7			V
		I <sub>C</sub> = 1 A, I <sub>B</sub> = 20 mA		50		mV
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA		40		mV
		I <sub>C</sub> = 6 A, I <sub>B</sub> = 300 mA		170		mV
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	I <sub>C</sub> = 6 A, I <sub>B</sub> = 6 mA			1.1	٧
		I <sub>C</sub> = 1 A, V <sub>CE</sub> = 1 V		350		
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	I <sub>C</sub> = 6 A, V <sub>CE</sub> = 1 V		100		
		I <sub>C</sub> = 20 A, V <sub>CE</sub> = 1 V		20		
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 0.1 A V <sub>CE</sub> = 10 V f = 100 MHz		100		MHz
C <sub>CBO</sub>	Collector-base capacitance (I <sub>E</sub> = 0)	f = 1 MHz V <sub>CB</sub> = 10 V		30		pF
	Resistive load Turn-on time	Ι_ = 15 Λ		TBD		ns
t <sub>on</sub>	Turn-on time	$I_C = 1.5 \text{ A}$ $V_{CC} = 10 \text{ V}$		וטט		119
t <sub>off</sub>	Turn-off time	$I_{B(on)} = -I_{B(off)} = 150 \text{ mA}$ $V_{BB(off)} = -5 \text{ V}$		TBD		ns

<sup>1.</sup> Pulse test: pulse duration  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %

#### 2.1 Test circuits

Figure 2. Resistive load switching



- 1. Fast electronic switch
- 2. Non-inductive resistor

## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. SOT-89 mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
A	1.40		1.60
В	0.44		0.56
B1	0.36		0.48
С	0.35		0.44
C1	0.35		0.44
D	4.40		4.60
D1	1.62		1.83
D3		0.90	
E	2.29		2.60
е	1.42		1.57
e1	2.92		3.07
Н	3.94		4.25
H1	2.70		3.10
К	1°		8°
L	0.89		1.20
R		0.25	
β		90°	

<u>D3</u> BOTTOM VIEW SIDE VIEW <u>C1</u> <u>D1</u> <u>C</u> B1(x2) D TOP VIEW 7098166\_REV\_E

Figure 3. SOT-89 drawings

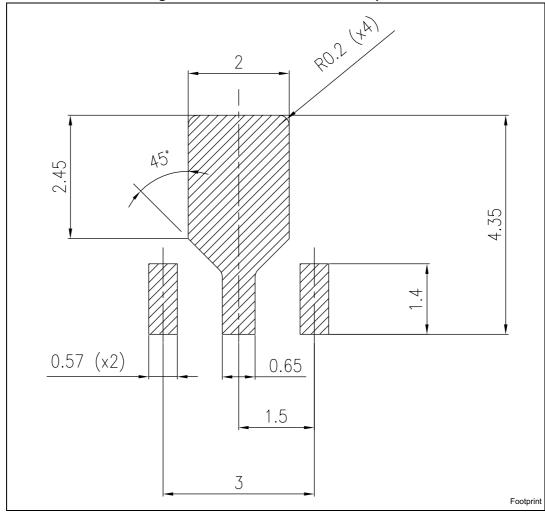


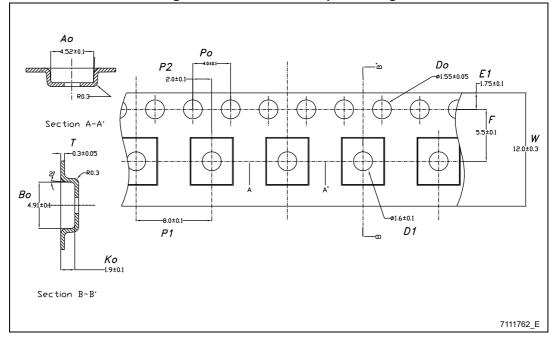
Figure 4. SOT-89 recommended footprint

## 4 Packaging mechanical data

Table 6. SOT-89 carrier tape dimensions

Dim	n	ım.
Dim.	Values	Tolerance
Ao	4.52	± 0.10
Во	4.91	± 0.10
Ко	1.90	± 0.10
F	5.50	± 0.10
E	1.75	± 0.10
W	12	± 0.30
P2	2	± 0.10
Po	4	± 0.10
P1	8	± 0.10
Т	0.30	± 0.10
D	Ø 1.55	± 0.05
D1	Ø 1.60	± 0.10

Figure 5. SOT-89 carrier tape drawing



PIN 1: BASE
PIN 2: COLLECTOR
PIN 3: EMITTER

SOT-89 top view

Figure 6. SOT-89 package orientation in carrier tape

3STF1640 Revision history

# 5 Revision history

Table 7. Document revision history

Date	Revision	Changes	
11-Sep-2012	1	Initial release.	
31-Oct-2012  Updated title and description on the cover page.  Document status promoted from target to preliminary data.		· · · · · · · · · · · · · · · · · · ·	
10-Apr-2013	3	Applications and Description have been modified in cover page.	

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